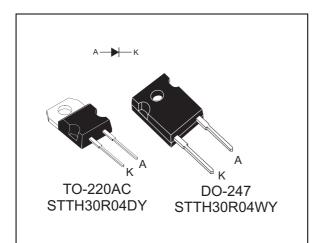


# STTH30R04-Y

**Datasheet - production data** 

### Automotive ultrafast recovery diode



#### Table 1. Device summary

Symbol	Value
I <sub>F(AV)</sub>	30 A
V <sub>RRM</sub>	400 V
T <sub>j (max)</sub>	175° C
V <sub>F (typ)</sub>	1.0 V
t <sub>rr (typ)</sub>	24 ns

#### Features

- Ultrafast switching
- Low reverse current
- Low thermal resistance
- Reduces switching and conduction losses
- High junction temperature
- AEC-Q101 qualified
- ECOPACK<sup>®</sup>2 compliant component

### Description

The compromise-free, high quality design of this diode has produced a device with low leakage current, regularly reproducible characteristics and intrinsic ruggedness. These characteristics make it ideal for heavy duty applications that demand long term reliability.

September 2013

This is information on a product in full production.

### 1 Characteristics

#### Table 2. Absolute ratings (limiting values at 25° C, unless otherwise specified)

Symbol	F	Value	Unit		
V <sub>RRM</sub>	Repetitive peak reverse voltage	400	V		
I <sub>F(RMS)</sub>	RMS forward current				А
I <sub>F(AV)</sub>	Average forward current, $\delta$ = 0.5 TO-220AC / DO-247 $T_c$ = 135° C				А
I <sub>FSM</sub>	Surge non repetitive forward current t <sub>p</sub> = 10 ms Sinusoidal				А
T <sub>stg</sub>	Storage temperature range				° C
Тj	Operating junction temperature range			-40 to +175	° C

#### Table 3. Thermal parameters

Symbol	Parameter		Value	Unit
R <sub>th(j-c)</sub>	Junction to case	TO-220AC / DO-247	0.8	°C/W

#### Table 4. Static electrical characteristics

Symbol	Parameter	Test conditions		Min	Тур	Max	Unit
		T <sub>j</sub> = 25° C				15	
$I_R^{(1)}$	IR <sup>(1)</sup> Reverse leakage current	T <sub>j</sub> = 100° C	$V_R = V_{RRM}$		3	30	μA
	T <sub>j</sub> = 125° C			15	150		
		T <sub>j</sub> = 25° C	1 15 0			1.35	
		T <sub>j</sub> = 150° C	I <sub>F</sub> = 15 A		0.83	1.04	
$V_F^{(2)}$	Forward voltage drop	T <sub>j</sub> = 25° C				1.55	V
		T <sub>j</sub> = 100° C	I <sub>F</sub> = 30 A			1.32	
		T <sub>j</sub> = 150° C			1.0	1.25	

1. Pulse test:  $t_p$  = 5 ms,  $\delta$  < 2 %

2. Pulse test:  $t_p$  = 380 µs,  $\delta$  < 2 %

To evaluate the conduction losses use the following equation: P = 0.95 x  $I_{F(AV)}$  + 0.01 x  ${I_F}^2_{(RMS)}$ 



Symbol	Parameter	Test conditions	Min	Тур	Max	Unit
		$I_F = 1 \text{ A, } dI_F/dt = -200 \text{ A}/\mu\text{s},$ $V_R = 30 \text{ V, } T_j = 25^{\circ} \text{ C}$		24	35	
t <sub>rr</sub>		I <sub>F</sub> = 1 A, dI <sub>F</sub> /dt = -15 A/μs, V <sub>R</sub> = 30 V, T <sub>j</sub> = 25° C		73	100	ns
		$I_F = 1 \text{ A}, I_R = 1 \text{ A},$ $I_{RR} = 0.25 \text{ A}, T_j = 25^{\circ} \text{ C}$			45	
I <sub>RM</sub>	Reverse recovery current	$I_F = 30 \text{ A}, \text{ dI}_F/\text{dt} = -200 \text{ A}/\mu\text{s},$ $V_R = 320 \text{ V}, \text{ T}_j = 125^\circ \text{ C}$		10	14	А
t <sub>fr</sub>	Forward recovery time	$I_F = 30 \text{ A}  dI_F/dt = 100 \text{ A}/\mu\text{s}$ $V_{FR} = 1.1 \text{ x} \text{ V}_{Fmax},  \text{T}_j = 25^{\circ} \text{ C}$			500	ns
V <sub>FP</sub>	Forward recovery voltage	$I_F = 30 \text{ A} \qquad dI_F/dt = 100 \text{ A}/\mu\text{s}$ $V_{FR} = 1.1 \text{ x} \text{ V}_{Fmax},  T_j = 25^{\circ}\text{ C}$		2.9		V

#### Table 5. Dynamic characteristics

#### Figure 1. Conduction losses versus average current

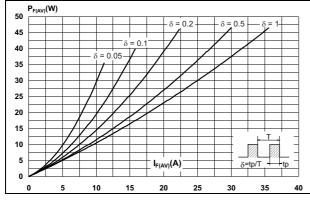


Figure 3. Relative variation of thermal impedance junction to case versus pulse duration



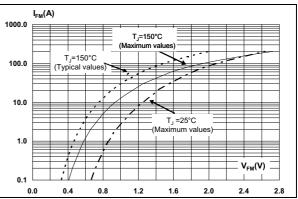


Figure 4. Peak reverse recovery current versus dl<sub>F</sub>/dt (typical values)

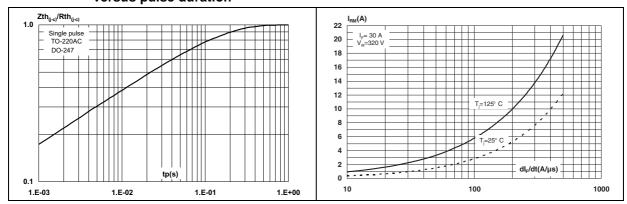
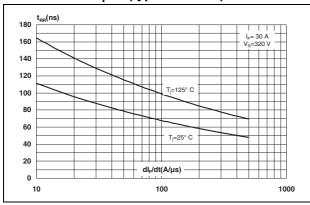




Figure 5. Reverse recovery time versus dl<sub>F</sub>/dt (typical values)



# Figure 7. Relative variations of dynamic parameters versus junction temperature

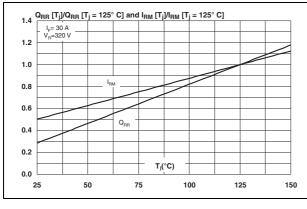


Figure 9. Forward recovery time versus dl<sub>F</sub>/dt (typical values)

#### Figure 8. Transient peak forward voltage versus dl<sub>F</sub>/dt (typical values)

100

Figure 6. Reverse recovery charges versus

dl<sub>F</sub>/dt (typical values)

T;=125° C

T<sub>i</sub>=25° C

- - -

dl<sub>⊧</sub>/dt(A/µs)

+++

1000

Q<sub>RR</sub>(nC)

I<sub>F</sub>= 30 A V<sub>B</sub>=320 V

750 700

650 600

550 500

450

400

350

300 250

200

150

100

50

0

10

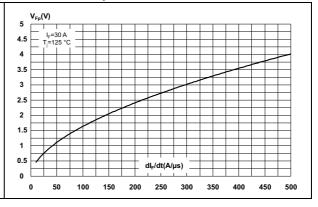
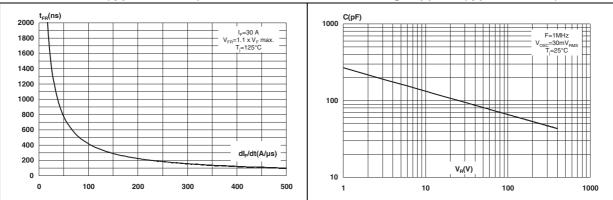


Figure 10. Junction capacitance versus reverse voltage applied (typical values)







### 2 Package information

- Epoxy meets UL94, V0
- Lead-free package
- Cooling method: by conduction (C)
- Recommended torque value: 0.4 to 0.6 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: *www.st.com.* ECOPACK<sup>®</sup> is an ST trademark.

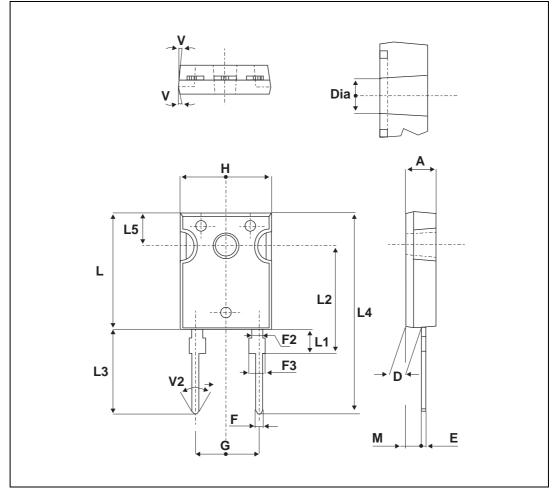


Figure 11. DO-247 dimension definitions



			0-247 diller			
			Dime	nsions		
Ref.		Millimeters		lillimeters		
	Min.	Тур.	Max.	Min.	Тур.	Max.
А	4.85		5.15	0.191		0.203
D	2.20		2.60	0.086		0.102
E	0.40		0.80	0.015		0.031
F	1.00		1.40	0.039		0.055
F2		2.00			0.078	
F3	2.00		2.40	0.078		0.094
G		10.90			0.429	
Н	15.45		15.75	0.608		0.620
L	19.85		20.15	0.781		0.793
L1	3.70		4.30	0.145		0.169
L2		18.50			0.728	
L3	14.20		14.80	0.559		0.582
L4		34.60			1.362	
L5		5.50			0.216	
М	2.00		3.00	0.078		0.118
V		5°			5°	
V2		60°			60°	
Dia.	3.55		3.65	0.139		0.143

Table 6. DO-247 dimension values



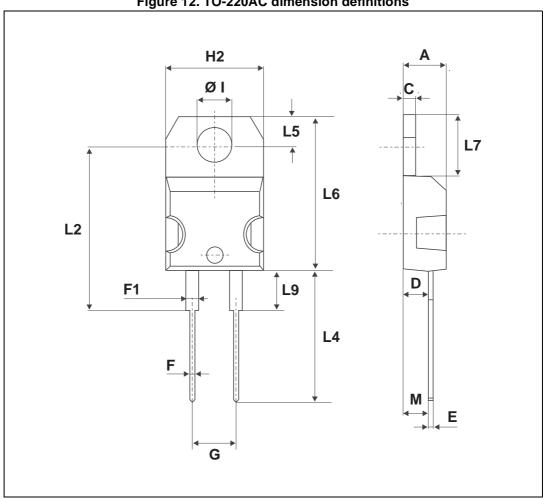


Figure 12. TO-220AC dimension definitions



			Dimer	nsions		
Ref.		Millimeters			Inches	
	Min.	Тур.	Max.	Min.	Тур.	Max.
А	4.40		4.60	0.173		0.181
С	1.23		1.32	0.048		0.051
D	2.40		2.72	0.094		0.107
Е	0.49		0.70	0.019		0.027
F	0.61		0.88	0.024		0.034
F1	1.14		1.70	0.044		0.066
G	4.95		5.15	0.194		0.202
H2	10.00		10.40	0.393		0.409
L2		16.4			0.645	
L4	13.00		14.00	0.511		0.551
L5	2.65		2.95	0.104		0.116
L6	15.25		15.75	0.600		0.620
L7	6.20		6.60	0.244		0.259
L9	3.50		3.93	0.137		0.154
М		2.6			0.102	
Diam. I	3.75		3.85	0.147		0.151

Table 7. TO-220AC dimension values



## **3** Ordering information

Table 8	B. Ord	lerina	informa	tion
Tuble C	. 010	i ci ili g	morma	

Order code	Marking	Package	Weight	Base qty	Delivery mode
STTH30R04DY	STTH30R04DY	TO-220AC	1.86 g	50	Tube
STTH30R04WY	STTH30R04WY	DO-247	4.40 g	30	Tube

## 4 Revision history

#### Table 9. Document revision history

Date	Revision	Description of changes
30-Sep-2013	1	First issue



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